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| INFORMATION DISCLOSURE STATEMENT TRANSMITTAL | | <i>Application Number</i> | |
| | | <i>Filing Date</i> | 10/584038 |
| | | <i>First Named Inventor</i> | HURKX, GODEFRIDUS, A., M. |
| | | <i>Group Art Unit</i> | |
| | | <i>Examiner Name</i> | |
| | | <i>Atty. Docket Number</i> | NL04 0842 US1 |

To Commissioner For Patents
Enclosed herewith is a Form PTO-1449, any required copies of documents listed thereon, and any concise explanation of their relevance is indicated below per 37 CFR 1.97.

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| | 1 | LIU J ET AL: "GALLIUM NITRIDE NANOWIRES DOPED WITH SILICON"; APPLIED PHYSICS LETTERS, AMERICAN INSTITUTE OF PHYSICS; NEW YORK US; VOL. 83, NO. 20; 17 NOV. 2003; PP 4241-4243. | | | |
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